Unit: mm

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (π-MOSVI)

2SK3868

Switching Regulator Applications

• Low drain-source ON resistance: R_{DS} (ON) = 1.3 Ω (typ.)

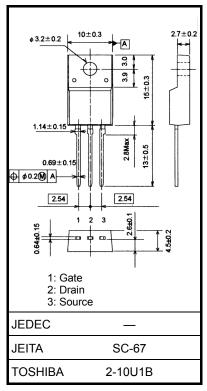
• High forward transfer admittance: |Y_{fs}| = 3 S (typ.)

• Low leakage current: $I_{DSS} = 100 \mu A (V_{DS} = 500 V)$

• Enhancement model: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristic | | Symbol | Rating | Unit |
|--|------------------------------|------------------|------------|------|
| Drain-source voltage | | V_{DSS} | 500 | V |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | V_{DGR} | 500 | V |
| Gate-source voltage | | V_{GSS} | ±30 | V |
| Drain current | DC (Note 1) | I _D | 5 | |
| | Pulse (t = 1 ms) (Note 1) | I _{DP} | 20 | Α |
| Drain power dissipati | on (Tc = 25°C) | P _D | 35 | W |
| Single pulse avalance | he energy (Note 2) | E _{AS} | 180 | mJ |
| Avalanche current | | I _{AR} | 5 | Α |
| Repetitive avalanche | energy (Note 3) | E _{AR} | 3.5 | mJ |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature | range | T _{stg} | -55 to 150 | °C |



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

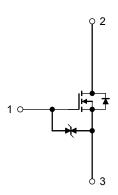
| Characteristic | Symbol | Max | Unit |
|--|------------------------|------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 3.57 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 62.5 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{Ch} = 25 $^{\circ}$ C (initial), L = 12.2 mH, I_{AR} = 5 A, R_G = 25 Ω

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



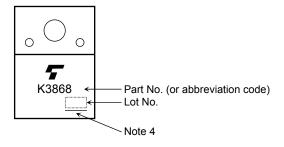
Electrical Characteristics (Ta = 25°C)

| Chai | racteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------|----------------|----------------------|--|-----|------|-----|------|
| Gate leakage cui | rent | I _{GSS} | $V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±10 | μΑ |
| Gate-source breakdown voltage | | V (BR) GSS | $I_G = \pm 10 \ \mu A, \ V_{DS} = 0 \ V$ | ±30 | _ | _ | V |
| Drain cutoff current | | I _{DSS} | V _{DS} = 500 V, V _{GS} = 0 V | _ | _ | 100 | μА |
| Drain-source bre | akdown voltage | V (BR) DSS | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$ | 500 | _ | _ | V |
| Gate threshold ve | oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source ON | resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 2.5 A | _ | 1.3 | 1.7 | Ω |
| Forward transfer | admittance | Y _{fs} | V _{DS} = 10 V, I _D = 2.5 A | 1.5 | 3.0 | _ | S |
| Input capacitance | | C _{iss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | _ | 550 | _ | pF |
| Reverse transfer capacitance | | C _{rss} | | _ | 7 | _ | |
| Output capacitance | | Coss | | _ | 70 | _ | |
| Switching time | Rise time | t _r | $\begin{array}{c c} 10 \text{ V} & \text{I}_D = 2.5 \text{ A} & \text{Vout} \\ \hline \text{VGS} & \text{V} & \text{RL} = \\ 15 \Omega & \text{90 } \Omega \\ \hline \end{array}$ $\begin{array}{c} \text{V}_{DD} \simeq 225 \text{ V} \\ \text{Duty} \leq 1\%, \ t_W = 10 \mu\text{s} \end{array}$ | _ | 10 | _ | |
| | Turn-on time | t _{on} | | _ | 20 | _ | 20 |
| | Fall time | t _f | | _ | 10 | _ | ns |
| | Turn-off time | t _{off} | | _ | 50 | _ | |
| Total gate charge | | Qg | | _ | 16 | _ | |
| Gate-source charge | | Q _{gs} | $V_{DD} \simeq 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}$ | _ | 10 | _ | nC |
| Gate-drain charge | | Q _{gd} | | _ | 6 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I_{DR} | _ | _ | _ | 5 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 20 | Α |
| Forward voltage (diode) | V_{DSF} | $I_{DR} = 5 A$, $V_{GS} = 0 V$ | | | -1.7 | V |
| Reverse recovery time | t _{rr} | $I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V},$ | | 150 | | ns |
| Reverse recovery charge | Qrr | dI _{DR} /dt = 100 A/μs | _ | 0.3 | _ | μС |

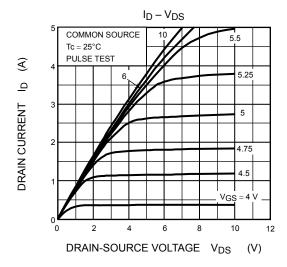
Marking

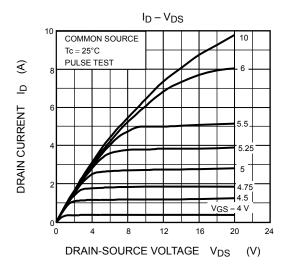


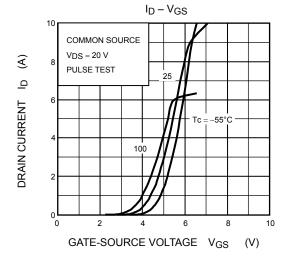
Note 4: A line under a Lot No. identifies the indication of product Labels.

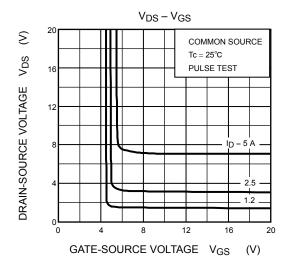
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

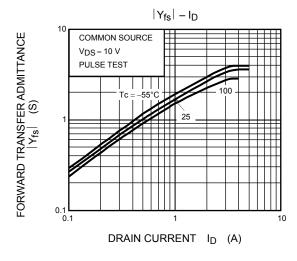
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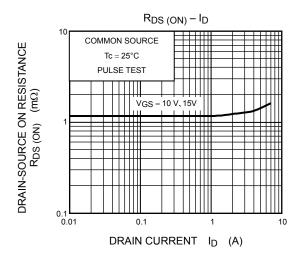




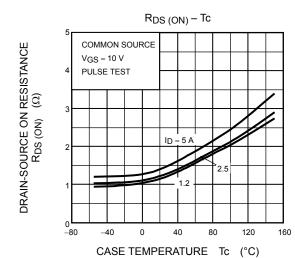


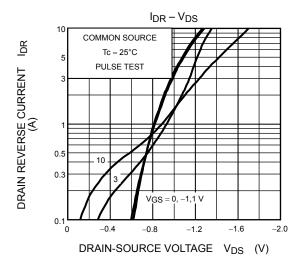


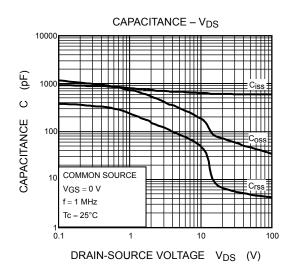


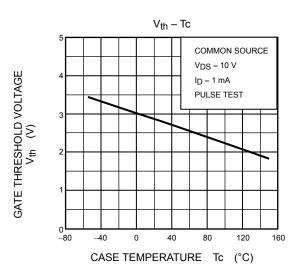


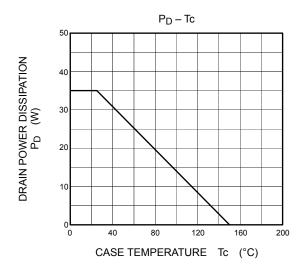
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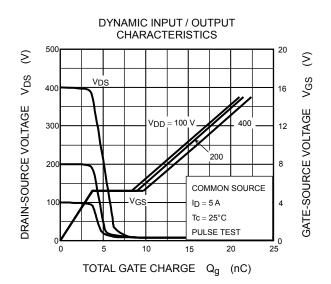




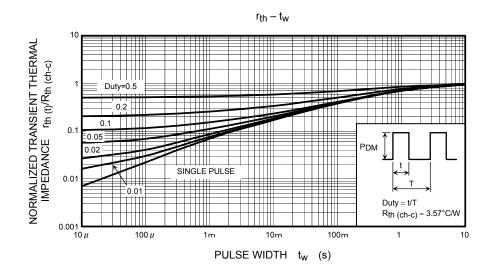


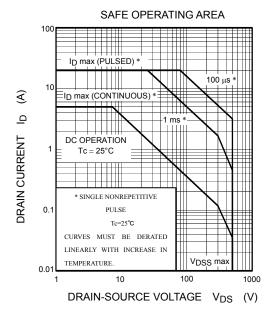


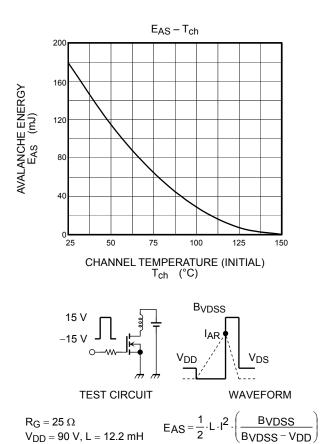




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 $V_{DD} = 90 \text{ V}, L = 12.2 \text{ mH}$

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